

### **General Description**

The MAX19993 dual-channel downconverter is designed

to provide 6.4dB of conversion gain, +27dBm input IP3,

15.4dBm 1dB input compression point, and a noise

figure of 9.8dB for 1200MHz to 1700MHz diversity

receiver applications. With an optimized LO frequency range of 1000MHz to 1560MHz, this mixer is ideal

for low-side LO injection architectures. High-side LO

injection is supported by the MAX19993A, which is pin-

In addition to offering excellent linearity and noise

performance, the MAX19993 also yields a high level of component integration. This device includes two

double-balanced passive mixer cores, two LO buffers, a

dual-input LO selectable switch, and a pair of differential

IF output amplifiers. Integrated on-chip baluns allow for

single-ended RF and LO inputs. The device requires a nominal LO drive of 0dBm and a typical supply current of

The MAX19993 is pin compatible with the MAX9985/

MAX19985A/MAX9995/MAX19993A/MAX19994/

MAX19994A/MAX19995/MAX19995A series of 700MHz

to 2200MHz mixers and pin similar to the MAX19997A/

MAX19999 series of 1850MHz to 4000MHz mixers,

making this entire family of downconverters ideal for

applications where a common PCB layout is used across

The device is available in a 6mm x 6mm, 36-pin TQFN

package with an exposed pad. Electrical performance is guaranteed over the extended temperature range, from

WCDMA/LTE Base Stations

**Fixed Broadband Wireless Access** 

or visit Maxim's website at www.maxim-ic.com.

Wireless Local Loop

Private Mobile Radios Military Systems

**Applications** 

multiple frequency bands.

 $T_{C} = -40^{\circ}C$  to  $+85^{\circ}C$ .

337mA at V<sub>CC</sub> = +5.0V or 275mA at V<sub>CC</sub> = +3.3V.

pin and functionally compatible with the MAX19993.

Features

- 1200MHz to 1700MHz RF Frequency Range
- 1000MHz to 1560MHz LO Frequency Range
- 50MHz to 500MHz IF Frequency Range
- ♦ 6.4dB Typical Conversion Gain
- 9.8dB Typical Noise Figure
- +27dBm Typical Input IP3
- 15.4dBm Typical Input 1dB Compression Point
- 72dBc Typical 2RF 2LO Spurious Rejection at PRF = -10dBm
- Dual Channels Ideal for Diversity Receiver **Applications**
- 47dB Typical Channel-to-Channel Isolation
- Low -6dBm to +3dBm LO Drive
- Integrated LO Buffer
- Internal RF and LO Baluns for Single-Ended Inputs
- ♦ Built-In SPDT LO Switch with 57dB LO-to-LO **Isolation and 50ns Switching Time**
- Pin Compatible with the MAX9985/19985A/ MAX9995/MAX19993A/MAX19994/MAX19994A/ MAX19995/MAX19995A Series of 700MHz to 2200MHz Mixers
- Pin Similar to the MAX19997A/MAX19999 Series of 1850MHz to 4000MHz Mixers
- Single +5V or +3.3V Supply
- External Current-Setting Resistors Provide Option for Operating Device in Reduced-Power/Reduced-**Performance Mode**

### **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE
MAX19993ETX+	-40°C to +85°C	36 TQFN-EP*
MAX19993ETX+T	-40°C to +85°C	36 TQFN-EP*

+Denotes a lead(Pb)-free/RoHS-compliant package. \*EP = Exposed pad.

T = Tape and reel.

### **MIXI/N**

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MAX19993

### **ABSOLUTE MAXIMUM RATINGS**

VCC to GND	0.3V to +5.5V
LO1, LO2 to GND	±0.3V
LOSEL to GND	0.3V to (V <sub>CC</sub> + 0.3V)
RFMAIN, RFDIV, and LO_ Input Pow	/er+15dBm
RFMAIN, RFDIV Current (RF is DC s	horted to GND
through a balun)	50mA
TAPMAIN, TAPDIV	0.3V to +2V
Any Other Pine to GND	0.2)/to(1/00 + 0.2)/)

Continuous Power Dissipation (Note 1)	8.7W
θJA (Notes 2, 3)	+38°C/W
θJC (Notes 1, 3)	7.4°C/W
Operating Temperature Range (Note 4) T <sub>C</sub> =	= -40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	+260°C

- **Note 1:** Based on junction temperature  $T_J = T_C + (\theta_{JC} \times V_{CC} \times I_{CC})$ . This formula can be used when the temperature of the exposed pad is known while the device is soldered down to a PCB. See the *Applications Information* section for details. The junction temperature must not exceed +150°C.
- **Note 2:** Junction temperature  $T_J = T_A + (\theta_{JA} \times V_{CC} \times I_{CC})$ . This formula can be used when the ambient temperature of the PCB is known. The junction temperature must not exceed +150°C.
- Note 3: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a fourlayer board. For detailed information on package thermal considerations, refer to <u>www.maxim-ic.com/thermal-tutorial</u>.
- Note 4: T<sub>C</sub> is the temperature on the exposed pad of the package. T<sub>A</sub> is the ambient temperature of the device and PCB.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### 5.0V SUPPLY DC ELECTRICAL CHARACTERISTICS

(*Typical Application Circuit*,  $V_{CC} = 4.75V$  to 5.25V, no input AC signals.  $T_C = -40^{\circ}C$  to  $+85^{\circ}C$ ,  $R1 = R4 = 681\Omega$ ,  $R2 = R5 = 1.82k\Omega$ . Typical values are at  $V_{CC} = 5.0V$ ,  $T_C = +25^{\circ}C$ , unless otherwise noted. All parameters are production tested.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	Vcc		4.75	5	5.25	V
Supply Current	ICC	Total supply current		337	400	mA
LOSEL Input High Voltage	Vih		2			V
LOSEL Input Low Voltage	VIL				0.8	V
LOSEL Input Current	IIH and IIL		-10		+10	μΑ

### 3.3V SUPPLY DC ELECTRICAL CHARACTERISTICS

(*Typical Application Circuit*, V<sub>CC</sub> = 3.0V to 3.6V, no input AC signals.  $T_C = -40^{\circ}C$  to  $+85^{\circ}C$ ,  $R1 = R4 = 681\Omega$ ,  $R2 = R5 = 1.43k\Omega$ . Typical values are at V<sub>CC</sub> = 3.3V,  $T_C = +25^{\circ}C$ , unless otherwise noted. Parameters are guaranteed by design and not production tested.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	Vcc		3.0	3.3	3.6	V
Supply Current	Icc	Total supply current (Note 5)		275		mA
LOSEL Input High Voltage	Vih			2		V
LOSEL Input Low Voltage	VIL			0.8		V

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RECOMMENDED AC OPERATING CONDITIONS							
PARAMETER	SYMBOL	CONDITIONS					
RF Frequency	fre	(Note 6)					

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PARAMETER	SYMBOL	CONDITIONS	MIN	IYP	WAX	UNITS
RF Frequency	fRF	(Note 6)	1200		1700	MHz
LO Frequency	fLO	(Note 6)	1000		1560	MHz
IF Frequency	fur	Using Mini-Circuits TC4-1W-17 4:1 trans- former as defined in the <i>Typical Application</i> <i>Circuit</i> , IF matching components affect the IF frequency range (Note 6)	100		500	
	ΤΙΕ	Using Mini-Circuits TC4-1W-7A 4:1 trans- former as defined in the <i>Typical Application</i> <i>Circuit</i> , IF matching components affect the IF frequency range (Note 6)	50 250		ΙνιΠΖ	
LO Drive Level	Plo	(Note 6)	-6		+3	dBm

### 5.0V SUPPLY, LOW-SIDE INJECTION AC ELECTRICAL CHARACTERISTICS

(Typical Application Circuit (see Table 1). R1 = R4 =  $681\Omega$ , R2 = R5 =  $1.82k\Omega$ , V<sub>CC</sub> = 4.75V to 5.25V, RF and LO ports are driven from  $50\Omega$  sources, PLO = -6dBm to +3dBm, PRF = -5dBm, fRF = 1200MHz to 1700MHz, fLO = 1060MHz to 1560MHz, fIF = 140MHz, fRF > fLO, TC = -40°C to +85°C. Typical values are at VCC = +5.0V, PRF = -5dBm, PLO = 0dBm, fRF = 1450MHz, fLO = 1310MHz, fIF = 140MHz, TC = +25°C. All parameters are guaranteed by design and characterization, unless otherwise noted.) (Note 7)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
			4.5	6.4	7.4	
Conversion Gain (Note 5)	GC	$T_{C} = +25^{\circ}C$	5.1	6.4	7.0	dB
		$T_{C} = +25^{\circ}C$ , $f_{RF} = 1427MHz$ to 1463MHz	5.2	6.4	6.9	
Conversion Gain Flatness	ΔGC	f <sub>RF</sub> = 1427MHz to 1463MHz		±0.03		dB
Gain Variation Over Temperature	TCCG	$T_C = -40^{\circ}C$ to $+85^{\circ}C$		-0.009		dB/°C
Input Compression Point	IP1dB	f <sub>RF</sub> = 1450MHz (Notes 5, 8)	12.9	15.4		dBm
		$f_{RF1} - f_{RF2} = 1MHz$ , $P_{RF} = -5dBm$ per tone	24.0	27.0		
Input Third-Order Intercept Point	IIP3	$ \begin{array}{l} f_{RF1}  f_{RF2} = 1 MHz, \mbox{-} P_{RF} = -5 dBm \mbox{ per tone}, \\ f_{RF} = 1427 MHz \mbox{ to } 1463 MHz, \mbox{-} T_C = +25 ^{\circ} C \\ (Note 5) \end{array} $	24.8	27.0		dBm
		$f_{RF1}$ - $f_{RF2}$ = 1MHz, $P_{RF}$ = -5dBm per tone, $f_{RF}$ = 1427MHz to 1463MHz (Note 5)	24.4	27.0		
Input Third-Order Intercept Point Variation Over Temperature	ТСирз	$f_{RF1}$ - $f_{RF2}$ = 1MHz, $P_{RF}$ = -5dBm per tone, T <sub>C</sub> = -40°C to +85°C		±0.5		dBm
		Single sideband, no blockers present		9.8	12.7	
Noise Figure (Note 9)	NFSSB	$f_{RF}$ = 1427MHz to 1463MHz, T <sub>C</sub> = +25°C, P <sub>LO</sub> = 0dBm, single sideband, no blockers present		9.8	11.0	dB
		$f_{RF}$ = 1427MHz to 1463MHz, $P_{LO}$ = 0dBm, single sideband, no blockers present		9.8	12.0	

### 5.0V SUPPLY, LOW-SIDE INJECTION AC ELECTRICAL CHARACTERISTICS (continued)

(*Typical Application Circuit* (see Table 1). R1 = R4 = 681 $\Omega$ , R2 = R5 = 1.82k $\Omega$ , V<sub>CC</sub> = 4.75V to 5.25V, RF and LO ports are driven from 50 $\Omega$  sources, P<sub>LO</sub> = -6dBm to +3dBm, P<sub>RF</sub> = -5dBm, f<sub>RF</sub> = 1200MHz to 1700MHz, f<sub>LO</sub> = 1060MHz to 1560MHz, f<sub>IF</sub> = 140MHz, f<sub>RF</sub> > f<sub>LO</sub>, T<sub>C</sub> = -40°C to +85°C. Typical values are at V<sub>CC</sub> = +5.0V, P<sub>RF</sub> = -5dBm, P<sub>LO</sub> = 0dBm, f<sub>RF</sub> = 1450MHz, f<sub>LO</sub> = 1310MHz, f<sub>IF</sub> = 140MHz, T<sub>C</sub> = +25°C. All parameters are guaranteed by design and characterization, unless otherwise noted.) (Note 7)

PARAMETER	SYMBOL	CONDIT	IONS	MIN	ТҮР	MAX	UNITS
Noise Figure Temperature Coefficient	TCNF	Single sideband, no blo $T_C = -40^{\circ}C$ to $+85^{\circ}C$	ockers present,		0.016		dB/°C
Noise Figure with Blocker	NFB	$\begin{array}{l} {\sf P}_{\sf BLOCKER} = +8d{\sf Bm}, \ {\sf f}_{\sf RF} = 1450{\sf MHz}, \\ {\sf f}_{\sf LO} = 1310{\sf MHz}, \ {\sf f}_{\sf BLOCKER} = 1550{\sf MHz}, \\ {\sf P}_{\sf LO} = 0d{\sf Bm}, \ {\sf V}_{\sf CC} = 5.0{\sf V}, \ {\sf T}_{\sf C} = +25{}^{\circ}{\sf C} \\ ({\sf Notes}\ 9,\ 10) \end{array}$			21.0	22.8	dB
		$f_{\rm RF} = 1450 \text{MHz},$	P <sub>RF</sub> = -10dBm	58	72		
		$f_{LO} = 1310MHz,$ $f_{SPUR} = 1380MHz$	P <sub>RF</sub> = -5dBm	53	67		dBc
2RF - 2LO Spur Rejection (Note 9)	2x2	$f_{RF} = 1450MHz,$ $f_{LO} = 1310MHz,$ $f_{SPUR} = 1380MHz,$	P <sub>RF</sub> = -10dBm	61	72		dDa
		$P_{LO} = 0dBm,$ $V_{CC} = 5.0V,$ $T_{C} = +25^{\circ}C$	P <sub>RF</sub> = -5dBm	56	67		авс
		$f_{RF} = 1450MHz,$	$P_{RF} = -10 dBm$	77	93		dPo
		$f_{SPUR} = 1356.67 MHz$	P <sub>RF</sub> = -5dBm	67	83		
3RF - 3LO Spur Rejection (Note 9)	3x3	$f_{RF} = 1450MHz, \\ f_{LO} = 1310MHz, \\ f_{SPUR} = 1356.67MHz, \\ P_{LO} = 0dBm, \\ V_{CC} = 5.0V, \\ T_{C} = +25^{\circ}C$	P <sub>RF</sub> = -10dBm	82	93		dDa
			P <sub>RF</sub> = -5dBm	72	83		
RF Input Return Loss		LO and IF terminated ir impedance, LO on	nto matched		21		dB
		LO port selected, RF ar matched impedance	nd IF terminated into		24		-10
LO Input Return Loss		LO port unselected, RF into matched impedance	and IF terminated		27		UB
IF Output Impedance	ZIF	Nominal differential imp outputs	bedance of the IF		200		Ω
IF Output Return Loss		RF terminated into $50\Omega$ , LO driven by $50\Omega$ source, IF transformed to $50\Omega$ using external components shown in the <i>Typical</i> <i>Application Circuit</i>			15		dB
RF-to-IF Isolation		(Note 5)			33		dB
LO Leakage at RF Port					-38		dBm
2LO Leakage at RF Port					-27		dBm

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5.0V SUPPLY, LOW-SIDE INJECTION AC ELECTRICAL CHARACTERISTICS (continued)

(*Typical Application Circuit* (see Table 1). R1 = R4 =  $681\Omega$ , R2 = R5 =  $1.82k\Omega$ , V<sub>CC</sub> = 4.75V to 5.25V, RF and LO ports are driven from  $50\Omega$  sources, P<sub>LO</sub> = -6dBm to +3dBm, P<sub>RF</sub> = -5dBm, f<sub>RF</sub> = 1200MHz to 1700MHz, f<sub>LO</sub> = 1060MHz to 1560MHz, f<sub>IF</sub> = 140MHz, f<sub>RF</sub> > f<sub>LO</sub>, T<sub>C</sub> =  $-40^{\circ}$ C to  $+85^{\circ}$ C. Typical values are at V<sub>CC</sub> = +5.0V, P<sub>RF</sub> = -5dBm, P<sub>LO</sub> = 0dBm, f<sub>RF</sub> = 1450MHz, f<sub>LO</sub> = 1310MHz, f<sub>IF</sub> = 140MHz, f<sub>IF</sub> = 140Mz, f<sub>IF</sub> = 140

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
LO Leakage at IF Port		(Note 5)		-18		dBm
Channel Isolation (Note 5)		RFMAIN converted power measured at IFDIV relative to IFMAIN, all unused ports terminated to $50\Omega$	43	47		dP
		RFDIV converted power measured at IFMAIN relative to IFDIV, all unused ports terminated to $50\Omega$	43	47		aB
LO-to-LO Isolation		$P_{LO1} = +3dBm, P_{LO2} = +3dBm,$ f <sub>LO1</sub> = 1310MHz, f <sub>LO2</sub> = 1311MHz (Note 5)	47	57		dB
LO Switching Time		50% of LOSEL to IF settled within 2 degrees		50		ns

### 3.3V SUPPLY, LOW SIDE INJECTION AC ELECTRICAL CHARACTERISTICS

(Typical Application Circuit (see Table 1). R1 = R4 = 681 $\Omega$ , R2 = R5 = 1.43k $\Omega$ . Typical values are at V<sub>CC</sub> = 3.3V, P<sub>RF</sub> = -5dBm, P<sub>LO</sub> = 0dBm, f<sub>RF</sub> = 1450MHz, f<sub>LO</sub> = 1310MHz, f<sub>IF</sub> = 140MHz, T<sub>C</sub> = +25°C, unless otherwise noted.) (Note 7)

PARAMETER	SYMBOL	CONDITIONS	MIN TYP	MAX	UNITS
Conversion Gain	GC	(Note 5)	6.2		dB
Conversion Gain Flatness	ΔGC	fRF = 1427MHz to 1463MHz	±0.05		dB
Gain Variation Over Temperature	TCCG	$T_C = -40^{\circ}C$ to $+85^{\circ}C$	-0.009	)	dB/°C
Input Compression Point	IP1dB	(Note 8)	12.8		dBm
Input Third-Order Intercept Point	IIP3	fRF1 - fRF2 = 1MHz	24.4		dBm
Input Third-Order Intercept Point Variation Over Temperature	TC <sub>IIP3</sub>	$f_{RF1} - f_{RF2} = 1MHz$ , $P_{RF} = -5dBm$ per tone, TC = -40°C to +85°C	±0.8		dBm
Noise Figure	NFSSB	Single sideband, no blockers present	9.8		dB
Noise Figure Temperature Coefficient	TCNF	Single sideband, no blockers present, T <sub>C</sub> = -40°C to +85°C	0.016		dB/°C
2PE 21 O Spur Principa	2 x 2	P <sub>RF</sub> = -10dBm	73		dPo
		P <sub>RF</sub> = -5dBm	68		UBC
	3 x 3	P <sub>RF</sub> = -10dBm	80		dRo
		P <sub>RF</sub> = -5dBm	70		UBC
RF Input Return Loss		LO and IF terminated into matched impedance, LO on	21		dB
LO Input Return Loss		LO port selected, RF and IF terminated into matched impedance	24		dP
		LO port unselected, RF and IF terminated into matched impedance	27		

## 3.3V SUPPLY, LOW SIDE INJECTION AC ELECTRICAL CHARACTERISTICS (continued)

(Typical Application Circuit (see Table 1). R1 = R4 = 681 $\Omega$ , R2 = R5 = 1.43k $\Omega$ . Typical values are at V<sub>CC</sub> = 3.3V, P<sub>RF</sub> = -5dBm, P<sub>LO</sub> = 0dBm, f<sub>RF</sub> = 1450MHz, f<sub>LO</sub> = 1310MHz, f<sub>IF</sub> = 140MHz, T<sub>C</sub> = +25°C, unless otherwise noted.) (Note 7)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	МАХ	UNITS
IF Output Return Loss		RF terminated into $50\Omega$ , LO driven by $50\Omega$ source, IF transformed to $50\Omega$ using external components shown in the <i>Typical Application Circuit</i>		15		dB
RF-to-IF Isolation				33		dB
LO Leakage at RF Port				-45		dBm
2LO Leakage at RF Port				-27		dBm
LO Leakage at IF Port				-22		dBm
Channel Isolation		RFMAIN converted power measured at IFDIV relative to IFMAIN, all unused ports terminated to $50\Omega$		47		
		RFDIV converted power measured at IFMAIN relative to IFDIV, all unused ports terminated to $50\Omega$		47		aв
LO-to-LO Isolation		$P_{LO1} = +3dBm, P_{LO2} = +3dBm,$ f <sub>LO1</sub> = 1310MHz, f <sub>LO2</sub> = 1311MHz		57		dB
LO Switching Time		50% of LOSEL to IF settled within 2 degrees		50		ns

Note 5: 100% production tested for functionality.

**Note 6:** Not production tested. Operation outside this range is possible, but with degraded performance of some parameters. See the *Typical Operating Characteristics* section.

**Note 7:** All limits reflect losses of external components, including a 0.5dB loss at  $f_{IF} = 140MHz$  due to the 4:1 transformer. Output measurements were taken at IF outputs of the *Typical Application Circuit*.

Note 8: Maximum reliable continuous input power applied to the RF or IF port of this device is +12dBm from a 50Ω source.

Note 9: Not production tested.

Note 10: Measured with external LO source noise filtered so the noise floor is -174dBm/Hz. This specification reflects the effects of all SNR degradations in the mixer, including the LO noise as defined in Application Note 2021: Specifications and Measurement of Local Oscillator Noise in Integrated Circuit Base Station Mixers.

MAX19993

# Dual, SiGe, High-Linearity, 1200MHz to 1700MHz Downconversion Mixer with LO Buffer/Switch



(*Typical Application Circuit* (see Table 1). Vcc = 5.0V,  $f_{RF} > f_{LO}$  for a 140MHz IF,  $P_{RF} = -5dBm$ ,  $P_{LO} = 0dBm$ ,  $T_{C} = +25^{\circ}C$ , unless otherwise noted.)



 $\label{eq:typical operating Characteristics (continued)} (Typical Application Circuit (see Table 1). V_{CC} = 5.0V, f_{RF} > f_{LO} for a 140MHz IF, P_{RF} = -5dBm, P_{LO} = 0dBm, T_{C} = +25^{\circ}C, unless otherwise noted.)$ 



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MAX19993

# Dual, SiGe, High-Linearity, 1200MHz to 1700MHz Downconversion Mixer with LO Buffer/Switch

 $\label{eq:transformation} \underbrace{ \mbox{Typical Operating Characteristics (continued)} }_{(Typical Application Circuit (see Table 1). Vcc = 5.0V, f_{RF} > f_{LO} \mbox{ for a 140MHz IF, P_{RF} = -5dBm, P_{LO} = 0dBm, T_{C} = +25^{\circ}C, \mbox{ unless otherwise noted.} }$ 



 $\label{eq:typical operating Characteristics (continued)} (Typical Application Circuit (see Table 1). V_{CC} = 5.0V, f_{RF} > f_{LO} for a 140MHz IF, P_{RF} = -5dBm, P_{LO} = 0dBm, T_{C} = +25^{\circ}C, unless otherwise noted.)$ 



**Typical Operating Characteristics (continued)** 

(*Typical Application Circuit* (see Table 1). Vcc = 5.0V,  $f_{RF} > f_{LO}$  for a 140MHz IF,  $P_{RF} = -5dBm$ ,  $P_{LO} = 0dBm$ ,  $T_C = +25^{\circ}C$ , unless otherwise noted.)



**Typical Operating Characteristics (continued)** (Typical Application Circuit (see Table 1). Vcc = 3.3V,  $f_{RF} > f_{LO}$  for a 140MHz IF,  $P_{RF} = -5$ dBm,  $P_{LO} = 0$ dBm,  $T_{C} = +25^{\circ}$ C, unless otherwise noted.)



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## **Typical Operating Characteristics (continued)**

(Typical Application Circuit (see Table 1). Vcc = 3.3V, fRF > fLO for a 140MHz IF, PRF = -5dBm, PLO = 0dBm, TC +25°C, unless otherwise noted.)







*Typical Operating Characteristics (continued)* (*Typical Application Circuit* (see Table 1). Vcc = 3.3V, f<sub>RF</sub> > f<sub>LO</sub> for a 140MHz IF, P<sub>RF</sub> = -5dBm, P<sub>LO</sub> = 0dBm, T<sub>C</sub> +25°C, unless otherwise noted.)



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### **Typical Operating Characteristics (continued)**

(*Typical Application Circuit* (see Table 1). V<sub>CC</sub> = 3.3V, f<sub>RF</sub> > f<sub>LO</sub> for a 140MHz IF, P<sub>RF</sub> = -5dBm, P<sub>LO</sub> = 0dBm, T<sub>C</sub> +25°C, unless otherwise noted.)



**Typical Operating Characteristics (continued)** 

(Typical Application Circuit (see Table 1). Vcc = 3.3V, fRF > fLO for a 140MHz IF, PRF = -5dBm, PLO = 0dBm, TC +25°C, unless otherwise noted.)



-40

-15

10 TEMPERATURE (°C)

35

60



### Pin Configuration



### **Pin Description**

PIN	NAME	FUNCTION
1	RFMAIN	Main Channel RF Input. Internally matched to 50 $\Omega$ . Requires an input DC-blocking capacitor.
2	TAPMAIN	Main Channel Balun Center Tap. Bypass to GND with 39pF and 0.033µF capacitors as close as possible to the pin with the smaller value capacitor closer to the part.
3, 5, 7, 12, 20, 22, 24, 25, 26, 34	GND	Ground
4, 6, 10, 16, 21, 30, 36	Vcc	Power Supply. Bypass to GND with capacitors as close as possible to the pin, as shown in the <i>Typical Application Circuit</i> .
8	TAPDIV	Diversity Channel Balun Center Tap. Bypass to GND with 39pF and 0.033µF capacitors as close as possible to the pin with the smaller value capacitor closer to the part.
9	RFDIV	Diversity Channel RF Input. Internally matched to 50 $\Omega$ . Requires an input DC-blocking capacitor.
11	IFD_SET	IF Diversity Amplifier Bias Control. Connect a resistor from this pin to ground to set the bias current for the diversity IF amplifier. See the <i>Typical Application Circuit</i> .
13, 14	IFD+, IFD-	Diversity Mixer Differential IF Output +/ Connect pullup inductors from each of these pins to V <sub>CC</sub> . See the <i>Typical Application Circuit</i> .
15	IND_EXTD	Diversity External Inductor Connection. Connect to ground through a $0\Omega$ resistor (0603) as close as possible to the pin. For improved RF-to-IF and LO-to-IF isolation, contact the factory for details.
17	LO_ADJ_D	LO Diversity Amplifier Bias Control. Connect a resistor from this pin to ground to set the bias current for the diversity LO amplifier. See the <i>Typical Application Circuit</i> .
18, 28	N.C.	No Connection. Not internally connected.
19	LO1	Local Oscillator 1 Input. This input is internally matched to $50\Omega$ . Requires an input DC-blocking capacitor.
23	LOSEL	Local Oscillator Select. Set this pin to high to select LO1. Set to low to select LO2.
27	LO2	Local Oscillator 2 Input. This input is internally matched to $50\Omega$ . Requires an input DC-blocking capacitor.
29	LO_ADJ_M	LO Main Amplifier Bias Control. Connect a resistor from this pin to ground to set the bias current for the main LO amplifier. See the <i>Typical Application Circuit</i> .
31	IND_EXTM	Main External Inductor Connection. Connect to ground through a $0\Omega$ resistor (0603) as close as possible to the pin. For improved RF-to-IF and LO-to-IF isolation, contact the factory for details.
32, 33	IFM-, IFM+	Main Mixer Differential IF Output -/+. Connect pullup inductors from each of these pins to V <sub>CC</sub> . See the <i>Typical Application Circuit</i> .
35	IFM_SET	IF Main Amplifier Bias Control. Connect a resistor from this pin to ground to set the bias current for the main IF amplifier. See the <i>Typical Application Circuit</i> .
	EP	Exposed Pad. Internally connected to GND. Solder this exposed pad to a PCB pad that uses mul- tiple ground vias to provide heat transfer out of the device into the PCB ground planes. These mul- tiple ground vias are also required to achieve the noted RF performance.

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## **Detailed Description**

The MAX19993 is a dual-channel downconverter designed to provide up to 6.4dB of conversion gain, +27dBm input IP3, 15.4dBm 1dB input compression point, and a noise figure of 9.8dB.

In addition to its high-linearity performance, the device achieves a high level of component integration. It integrates two double-balanced mixers for two-channel downconversion. Both the main and diversity channels include a balun and matching circuitry to allow  $50\Omega$ single-ended interfaces to the RF ports and the two LO ports. An integrated single-pole/double-throw (SPDT) switch provides 50ns switching time between the two LO inputs with 57dB of LO-to-LO isolation and -38dBm of LO leakage at the RF port. Furthermore, the integrated LO buffers provide a high drive level to each mixer core, reducing the LO drive required at the device's inputs to a range of -6dBm to +3dBm. The IF ports for both channels incorporate differential outputs for downconversion, which is ideal for providing enhanced 2RF - 2LO performance.

The device is specified to operate over an RF input range of 1200MHz to 1700MHz, an LO range of 1000MHz to 1560MHz, and an IF range of 50MHz to 500MHz. The external IF components set the lower frequency range. See the *Typical Operating Characteristics* section for details. Operation beyond these ranges is possible; see the *Typical Operating Characteristics* section for additional information. Although this device is optimized for lowside LO injection applications, it can operate in highside LO injection modes as well. However, performance degrades as fLO continues to increase. Contact the factory for a variant with increased high-side LO performance.

### **RF Port and Balun**

The RF input ports of both the main and diversity channels are internally matched to  $50\Omega$ , requiring no external matching components. A DC-blocking capacitor is required as the input is internally DC shorted to ground through the on-chip balun. The RF port input return loss is typically better than 19dB over the 1400MHz to 1700MHz RF frequency range.

### LO Inputs, Buffer, and Balun

The device is optimized for a 1000MHz to 1560MHz LO frequency range. As an added feature, the device includes an internal LO SPDT switch for use in frequency-hopping applications. The switch selects one of the two single-ended LO ports, allowing the external oscillator to settle on a particular frequency before it is switched in. LO switching time is typically 50ns, which is more than adequate for typical GSM applications. If frequency hopping is not employed, simply set the switch to either of the LO inputs. The switch is controlled by a digital input (LOSEL), where logic-high selects LO1 and logic-low selects LO2. LO1 and LO2 inputs are internally matched to  $50\Omega$ , requiring only 39pF DC-blocking capacitors.

If LOSEL is connected directly to a logic source, then voltage **MUST** be applied to VCC before digital logic is applied to LOSEL to avoid damaging the part. Alternatively, a 1k $\Omega$  resistor can be placed in series at the LOSEL to limit the input current in applications where LOSEL is applied before VCC.

The main and diversity channels incorporate a two-stage LO buffer that allows for a wide-input power range for the LO drive. The on-chip low-loss baluns, along with LO buffers, drive the double-balanced mixers. All interfacing and matching components from the LO inputs to the IF outputs are integrated on-chip.

### **High-Linearity Mixer**

The core of the device's dual-channel downconverter consists of two double-balanced, high-performance passive mixers. Exceptional linearity is provided by the large LO swing from the on-chip LO buffers. When combined with the integrated IF amplifiers, the cascaded IIP3, 2RF - 2LO rejection, and noise-figure performance are typically +27dBm, 72dBc, and 9.8dB, respectively.

### **Differential IF**

The device has a 50MHz to 500MHz IF frequency range, where the low-end frequency depends on the frequency response of the external IF components. Note that these differential ports are ideal for providing enhanced IIP2 performance. Single-ended IF applications require a 4:1 (impedance ratio) balun to transform the 200 $\Omega$  differential IF impedance to a 50 $\Omega$  single-ended system. After the balun, the return loss is typically 15dB. The user can use a differential IF amplifier on the mixer IF ports, but a DC block is required on both IFD+/IFD- and IFM+/IFM- ports to keep external DC from entering the IF ports of the mixer.

# MAX19993

# Applications Information

Input and Output Matching

The RF and LO inputs are internally matched to  $50\Omega$ . No matching components are required. The RF port input return loss is typically better than 19dB over the 1400MHz to 1700MHz RF frequency range and return loss at the LO ports are typically better than 15dB over the entire LO range. RF and LO inputs require only DC-blocking capacitors for interfacing.

The IF output impedance is  $200\Omega$  (differential). For evaluation, an external low-loss 4:1 (impedance ratio) balun transforms this impedance to a  $50\Omega$  single-ended output. See the *Typical Application Circuit*.

### **Reduced-Power Mode**

Each channel of the device has two pins (LO\_ADJ\_D/ LO\_ADJ\_M, IFD\_SET/IFM\_SET) that allow external resistors to set the internal bias currents. Nominal values for these resistors are given in Table 1. Larger value resistors can be used to reduce power dissipation at the expense of some performance loss. If  $\pm 1\%$  resistors are not readily available, substitute with  $\pm 5\%$  resistors.

Significant reductions in power consumption can also be realized by operating the mixer with an optional 3.3V supply voltage. Doing so reduces the overall power consumption by approximately 46%. See the *3.3V Supply AC Electrical Characteristics* table and the relevant 3.3V curves in the *Typical Operating Characteristics* section.

### **IND\_EXT\_** Inductors

The default application circuit calls for connecting IND\_EXT\_ (pins 15 and 31) to ground through a 0 $\Omega$  resistor (0603) as close as possible to the pin. For improved RF-to-IF and LO-to-IF isolation, contact the factory for details.

### Layout Considerations

A properly designed PCB is an essential part of any RF/microwave circuit. Keep RF signal lines as short as possible to reduce losses, radiation, and inductance. The load impedance presented to the mixer must be such that any capacitance from both IF- and IF+ to ground does not exceed several picofarads. For the best performance, route the ground pin traces directly to the exposed pad under the package. The PCB exposed pad **MUST** be connected to the ground plane of the PCB. It is suggested that multiple vias be used to connect this pad to the lower-level ground planes. This method provides a good RF/thermal-conduction path for the device. Solder the exposed pad on the bottom of the device package to the PCB. The MAX19993 evaluation kit can be used as a reference for board layout. Gerber files are available upon request at www.maxim-ic.com.

### **Power-Supply Bypassing**

Proper voltage-supply bypassing is essential for highfrequency circuit stability. Bypass each V<sub>CC</sub> pin and TAPMAIN/TAPDIV with the capacitors shown in the *Typical Application Circuit*. See Table 1 for component values. Place the TAPMAIN/TAPDIV bypass capacitors to ground within 100 mils of the pin.

### **Exposed Pad RF/Thermal Considerations**

The exposed pad (EP) of the MAX19993's 36-pin TQFN-EP package provides a low thermal-resistance path to the die. It is important that the PCB on which the device is mounted be designed to conduct heat from the EP. In addition, provide the EP with a low-inductance path to electrical ground. The EP **MUST** be soldered to a ground plane on the PCB, either directly or through an array of plated via holes.

### **Typical Application Circuit**



### **Table 1. Component Values**

DESIGNATION	QTY	DESCRIPTION	COMPONENT SUPPLIER
C1, C2, C7, C8, C14, C16	6	39pF microwave capacitors (0402)	Murata Electronics North America, Inc.
C3, C6	2	0.033µF microwave capacitors (0603)	Murata Electronics North America, Inc.
C4, C5	2	0402, not used	—
C9, C13, C15, C17, C18	5	0.01µF microwave capacitors (0402)	Murata Electronics North America, Inc.

DESIGNATION	QTY	DESCRIPTION	COMPONENT SUPPLIER
C10, C11, C12, C19, C20, C21	6	150pF microwave capacitors (0603)	Murata Electronics North America, Inc.
L1, L2, L4, L5	4	330nH wire-wound high-Q inductors (0805)	Coilcraft, Inc.
L3, L6	2	$0\Omega$ resistors (0603). For improved RF-to-IF and LO-to-IF isolation, contact factory for details.	Digi-Key Corp.
L7, L8	2	Additional tuning elements (0402, not used)	—
R1, R4	2	681Ω ±1% resistors (0402). Used for Vcc = 5.0V applications. Larger values can be used to reduce power at the expense of some performance loss. 681Ω ±1% resistors (0402). Used for Vcc = 3.3V applications.	Digi-Key Corp.
R2, R5	2	1.82k $\Omega \pm 1\%$ resistors (0402). Used for V <sub>CC</sub> = 5.0V applications. Larger values can be used to reduce power at the expense of some performance loss. 1.43k $\Omega \pm 1\%$ resistors (0402). Used for V <sub>CC</sub> = 3.3V applications.	Digi-Key Corp.
R3, R6	2	$0\Omega$ resistors (1206)	Digi-Key Corp.
T1, T2	2	4:1 transformers (200:50) TC4-1W-7A	Mini-Circuits
U1	1	MAX19993 IC (36 TQFN-EP)	Maxim Integrated Products, Inc.

### Table 1. Component Values (continued)

**Chip Information** 

PROCESS: SiGe BiCMOS

### **Package Information**

For the latest package outline information and land patterns, go to **www.maxim-ic.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE	PACKAGE	OUTLINE	LAND
TYPE	CODE	NO.	PATTERN
36 Thin QFN-EP	T3666+2	<u>21-0141</u>	<u>90-0049</u>

### **Revision History**

REVISION	REVISION	DESCRIPTION	PAGES
NUMBER	DATE		CHANGED
0	6/10	Initial release	—

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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